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Note: xxxFW (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX273F,TC74LCX273FW,TC74LCX273FT,TC74LCX273FK

Low-Voltage Octal D-Type Flip-Flop with Clear with 5-V Tolerant Inputs and Outputs

The TC74LCX273F/FW/FT/FK is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low-power dissipation.

The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and a clear input ($\overline{\text{CLR}}$). When the $\overline{\text{CLR}}$ input is low, the eight outputs are at a low logic level.

All inputs are equipped with protection circuits against static discharge.

Features

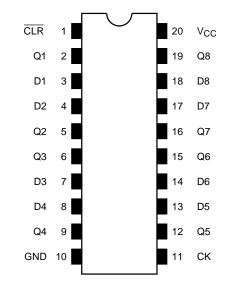
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 8.5 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: |IOH|/IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection is provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 273 type

Japan.
TC74LCX273F
TURRERRERRE
SOP20-P-300-1.27A
THREARCHER
SOP20-P-300-1.27 TC74LCX273FW
THUTTURE
SOL20-P-300-1.27 TC74LCX273FT
- TOTAL
TSSOP20-P-0044-0.65A TC74LCX273FK
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VSSOP20-P-0030-0.50

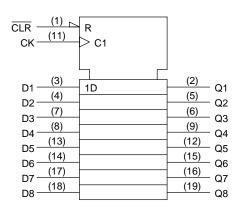
Weight	
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)

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Pin Assignment (top view)



IEC Logic Symbol

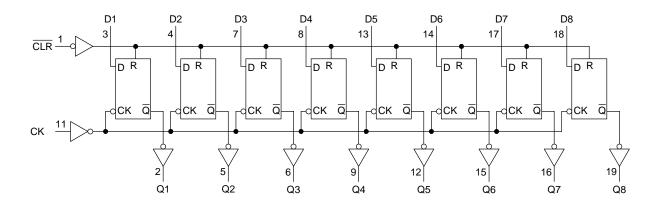


Truth Table

	Inputs		Outputs	Function
CLR	D	СК	Q	T unction
L	Х	Х	L	Clear
Н	L		L	—
н	Н		Н	—
Н	Х		Qn	No change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc	2.0 to 3.6	V	
rower supply voltage	v.cc	-1.5 to 3.6 (Note 2)	v	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to 5.5 (Note 3)	V	
		0 to V _{CC} (Note 4)	v	
	lau/lau	±24 (Note 5)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 6)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: $V_{CC} = 0 V$

- Note 4: High or low state
- Note 5: $V_{CC}=$ 3.0 to 3.6 V $\,$
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{IN}=0.8 \mbox{ to } 2.0 \mbox{ V}, \mbox{ } V_{CC}=3.0 \mbox{ V}$

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Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test		Min	Мах	Unit	
Charac	ciensiles	Symbol	Test			IVIII	iviax	Unit
Input voltage	H-level	V _{IH}			2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}			2.7 to 3.6	_	0.8	v
			I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_		
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	V
		-		I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	
		Vol	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level			I _{OL} = 12 mA	2.7	_	0.4	
	L-IEVEI	VOL		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage cu	rrent	l _{IN}	$V_{IN} = 0$ to 5.5 V	V _{IN} = 0 to 5.5 V		_	±5.0	μA
Power-off leakag	e current	I _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0	_	10.0	μA
Quiescent supply current		laa	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	10.0	
		ICC	V _{IN} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μA
Increase in Icc p	er input	Δl _{CC}	$V_{IN} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition		Min	Мах	Unit
Characteristics	Symbol	Symbol Test Condition		IVIIII	IVIAX	Unit
Maximum clock frequency	f _{MAX}	(Figure 1, Figure 2)	2.7	_	_	MHz
Maximum clock nequency	MAX		$\textbf{3.3}\pm\textbf{0.3}$	150	_	
Propagation delay time (CK-Q)	t PLH	(Figure 1, Figure 2)	2.7	_	9.5	ns
Propagation delay time (CK-Q)	tPHL		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	115
Propagation delay time (\overline{CLR} -Q)	(Figure 1 Figure 2)	(Figure 1, Figure 3)	2.7	_	9.5	ns
	^t PHL		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	115
Minimum pulse width (CK)	t _{w (H)}	(Figure 1, Figure 2)	2.7	3.3	_	ns
	t _{w (L)}			3.3	—	115
Minimum pulse width (\overline{CLR})	t _{w (L)} (Figure 3)	(Figure 3)	2.7	3.3		200
		$\textbf{3.3}\pm\textbf{0.3}$	3.3	_	ns	
Minimum setup time	ts	(Figure 1, Figure 2)	2.7	2.5	_	ns
Minimum Setup time	۲S		$\textbf{3.3}\pm\textbf{0.3}$	2.5	n:	
Minimum hold time	+.	(Figure 1, Figure 2)	2.7	1.5	_	ns
	t _h		$\textbf{3.3}\pm\textbf{0.3}$	1.5	_	115
Minimum removal time	+		2.7	2.5	_	20
Minimum removal ume	t _{rem}	(Figure 4)	$\textbf{3.3}\pm\textbf{0.3}$	2.0	_	ns
	t _{osLH}	(Note)	2.7	_		ns
Output to output skew	t _{osHL}	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	115

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

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Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 3.3 V, V_{IL} = 0 V$	3.3	0.8	V
Quiet output minimum dynamic V_{OL}	$ V_{OLV} $	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		3.3	7	pF
Output capacitance	C _{OUT}	_	0	8	pF
Power dissipation capacitance	C _{PD}	$f_{\text{IN}} = 10 \text{ MHz} \tag{Note}$	3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

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AC Test Circuit

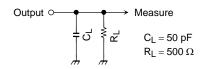
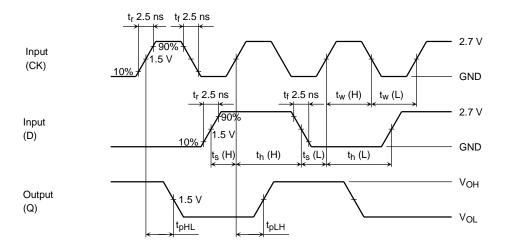


Figure 1

AC Waveform



 $\label{eq:Figure 2} \quad t_{pLH}, \, t_{pHL}, \, t_w, \, t_s, \, t_h$

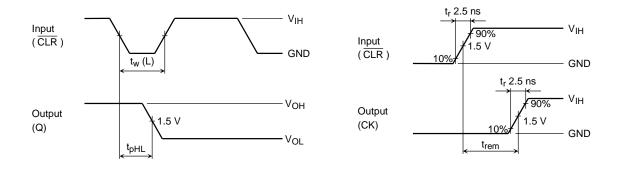
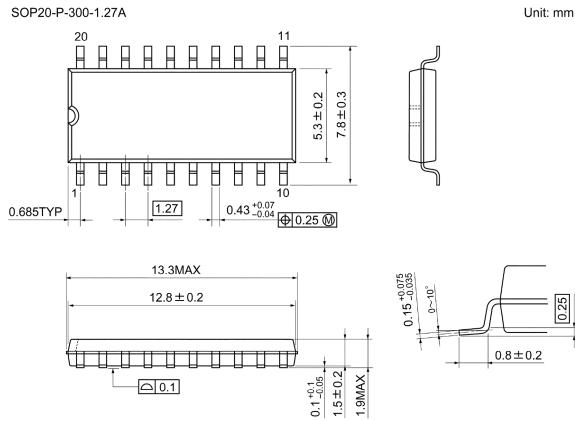


Figure 3 t_{pHL}

Figure 4 trem

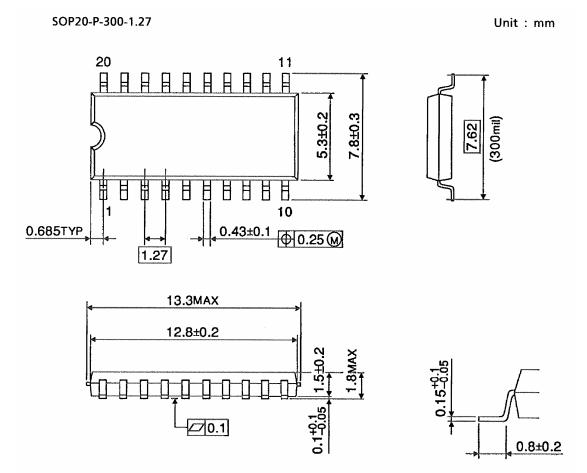
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Package Dimensions



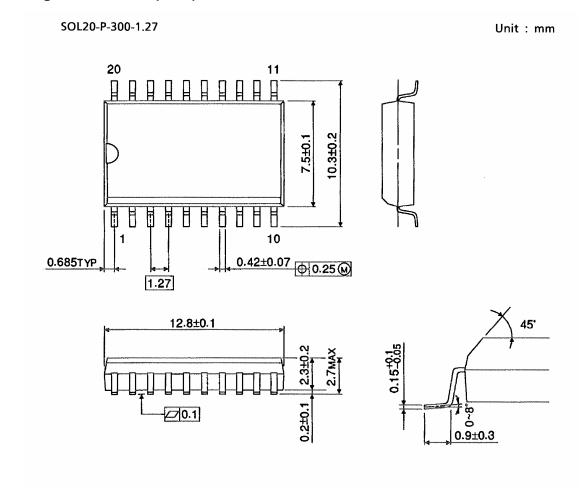
Weight: 0.22 g (typ.)

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions (Note)



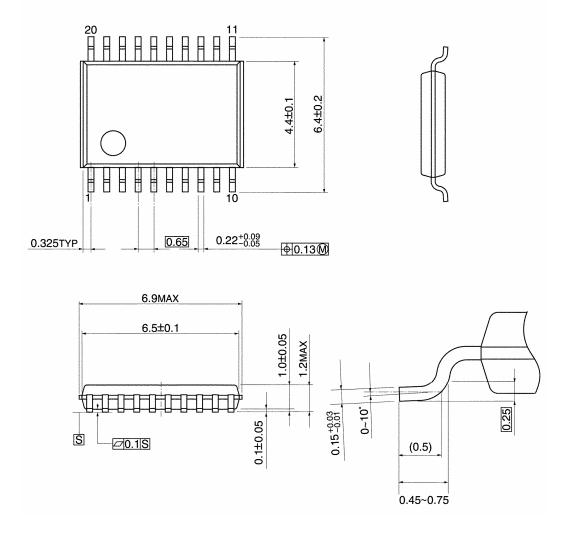
Note: This package is not available in japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm

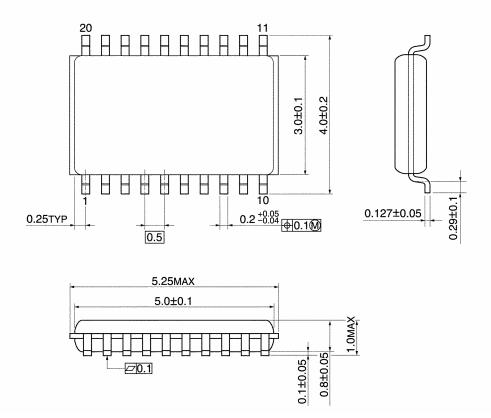


Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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